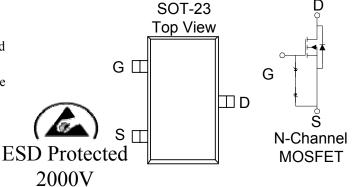
N-Channel 40-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe SOT-23 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$		
40	$86@V_{CS} = 10V$	5.2		
	$128@V_{CS}=4.5V$	3.7		



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Limit	Units
Drain-Source Voltage			40	V
Gate-Source Voltage		V_{GS}	±20	V
	$T_A=25^{\circ}C$	I_{D}	5.2	
Continuous Drain Current ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1D	4.1	A
Pulsed Drain Current ^b		I_{DM}	30	
Continuous Source Current (Diode Conduction) ^a		I_S	1.6	A
D D: a	$T_A=25^{\circ}C$	$\bigcup_{\mathbf{D}_{-}}$	1.3	W
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	Гр	0.8	
Operating Junction and Storage Temperature Range		T_{J}, T_{stg}	-55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
a	t <= 5 sec	n	100	°C/W	
Maximum Junction-to-Ambient ^a	Steady-State	$R_{\theta JA}$	166	°C/W	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

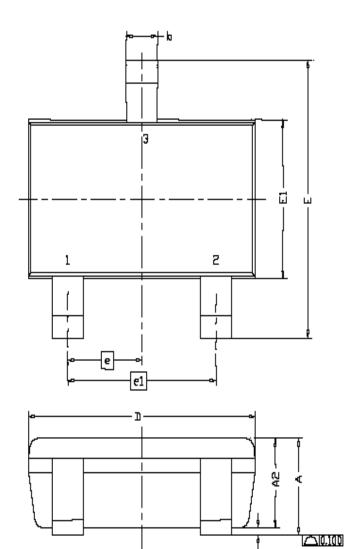
Demonstra	6 11	Total Constitution	Limits			T L.*4
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Cate-Threshold Voltage	VGS(th)	V _{DS} =V _{GS} , I _D =250uA	1			V
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{CS} = 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Gurrent	Ioss	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA
Zero Cite voltage Dain Caren	1033	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			25	
On-State Drain Gurrent ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α
D : G . D : A	4	$V_{GS} = 10 \text{ V, ID} = 5.2 \text{ A}$			86	mΩ
Drain-Source On-Resistance ^A	IDS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 3.7 \text{ A}$			128	
Forward Tranconductance ^A	gs	$V_{DS} = 15 \text{ V}, I_D = 5.2 \text{ A}$		40		S
Diode Forward Voltage	V _{SD}	$I_S = 2.3 A, V_{GS} = 0 V$		0.7		V
Dynamic ^b						
Total Gate Charge	Qg	Voc = 15 V Voc = 45 V		4.0		
Cate-Source Charge	Qgs	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_D = 5.2 \text{ A}$		1.1		nС
Gate-Drain Charge	Qgd	ID-3.2A		1.4		
Turn-On Delay Time	td(on)			16		
Rise Time	$t_{\rm r}$	V_{DD} =25 V, R_L =25 Ω , I_D =1 A, V_{GEN} =10 V		5		nS
Turn-Off Delay Time	td(off)			23		
Fall-Time	t f			3		

Notes

- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information



DIM.	MILLIMETERS			
יויודת	MIN	NDM	MAX	
Α	0.935	0.95	1.10	
A1	0.01	-	0.10	
A2	0.85	0.90	0.925	
Ф	0.30	0.40	0.50	
u	0.10	0.15	0.25	
D	2.70	2.90	3.10	
П	2.60	2.80	3.00	
E1	1.40	1.60	1.80	
6	0.95 BSC			
el	1.90 BSC			
L	0.30	0.40	0.60	
L1	0.60REF			
LZ	0.25BSC			
R	0.10			
θ	Q*	4*	8*	
81	7*N□M			

